Supplementary Information

High Luminance of CuInS$_2$-based Yellow Quantum Dot Light Emitting Diodes Fabricated by All-solution Processing

Jingling Li,\textsuperscript{ab} Hu Jin,\textsuperscript{ab} Kelai Wang,\textsuperscript{ac} Dehui Xie,\textsuperscript{acd} Dehua Xu,\textsuperscript{abd} Xueqing Xu\textsuperscript{*ab} and Gang Xu\textsuperscript{ab}

\textsuperscript{a}Key Laboratory of Renewable Energy, Guangzhou Institute of Energy Conversion, Chinese Academy of Sciences, Guangzhou 510640, China
\textsuperscript{b}University of Chinese Academy of Sciences, Beijing 100049, China
\textsuperscript{c}Guangdong University of Technology, School of Chemical Engineering and Light Industry, Guangzhou 510006, China
\textsuperscript{d}Nano Science and Technology Institute, University of Science and Technology of China, Suzhou 215123, China

* Corresponding author. Email address: xuxq@ms.giec.ac.cn
Figure S1 shows the FTIR spectra of pure DDT and EHT. In spectrum of DDT, vibrations of symmetrical and asymmetrical stretching of C–H bonds appear some red-shifted as compared with the corresponding ones in EHT. Besides, we find that obvious differences of these two spectra emerge in the so-called fingerprint region where mainly belongs to the vibration of C–S bonds. Vibrational modes of C–S bonds in DDT and EHT locate at 654 cm$^{-1}$ and 669 cm$^{-1}$, respectively.

![FTIR spectra of DDT and EHT](image)

**Figure S1.** FTIR spectra of DDT and EHT.
Figure S2 depicts the structural and optical properties of ZnO nanoparticles. TEM images show that the ZnO nanoparticles have a uniform size of 4.8 nm and possess a good crystallinity. XRD diffractional pattern reveals that ZnO nanoparticles are crystalline and have a wurtzite structure similar to that of bulk ZnO. An obvious absorption peak at 333 nm in UV-Vis spectrum is observed which corresponds to a band gaps of 3.72 eV. In addition, photoluminescent spectrum of ZnO nanoparticles exhibits a broad defect-related emission with a 517 nm central fluorescent peak.

Figure S2. Structural and optical properties of ZnO nanoparticles measured by TEM, XRD, UV-vis absorption and PL measurements. (a) TEM image of ZnO nanoparticles. Inset of high-resolution TEM image shows that the ZnO have a good crystallinity. (b) Histogram of ZnO nanoparticles size based on the survey of 100 particles from different regions of the grid. (c) XRD pattern of ZnO nanoparticles. (d) UV-Vis absorption spectrum and the corresponding PL spectrum of ZnO nanoparticles.
Figure S3 shows the voltage dependence of current density in electron devices. These current density-voltage characteristics are mainly affected by the thickness of ZnO layer. It shows that, at a given voltage, a thicker ZnO layer possibly results in a higher current density.

![Figure S3](image)

**Figure S3.** Current density-voltage characteristic curves in electron-only devices with different thickness of ZnO layer.
Figure S4 shows the structure schematic of electron-only and hole-only devices and their corresponding energy band diagram. In electron-only devices, two ZnO layers in electron-only devices are used to block the hole injection from electrode. Similarly, the two PVK layers used in hole-only devices prevent the electrons from injecting to the QDs layer.

Figure S4. (a) Structure schematic and (b) energy band diagram of electron-only devices. (c) Structure schematic and (d) energy band diagram of hole-only devices.